UNISONIC TECHNOLOGIES CO., LTD

UT5504 **Power MOSFET**

P-CHANNEL LOGIC LEVEL **ENHANCEMENT MODE FIELD EFFECT TRANSISTOR**

DESCRIPTION

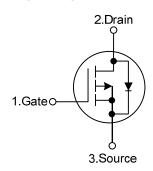
The UTC UT5504 is a P-channel enhancement mode power MOSFET, providing customers fast switching, ruggedized device design, low on-resistance and cost-effectiveness by UTC's advanced technology.

The UTC UT5504 can be used in applications such as DC/DC converters, all commercial-industrial surface mount and low voltage devices.

FEATURES

- * Low On-Resistance
- * Simple Drive Requirement
- * Fast Switching Speed

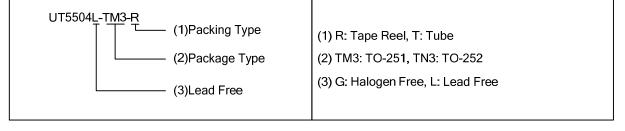
SYMBOL

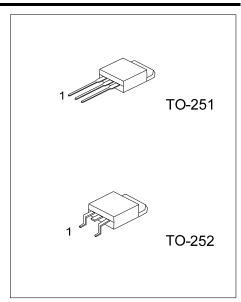


ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UT5504L-TM3-T	UT5504G-TM3-T	TO-251	G	D	S	Tube	
UT5504L-TN3-R	UT5504G-TN3-R	TO-252	G	D	S	Tape Reel	
UT5504L-TN3-T	UT5504G-TN3-T	TO-252	G	D	S	Tube	

Note: Pin Assignment: G: Gate, D: Drain, S: Source





■ **ABSOLUTE MAXIMUM RATINGS** (T_C = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DS}	-40	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current	T _C =25°C	l _D	-8	^
	T _C =70°C		-6	Α
Pulsed Drain Current		I _{DM}	-32	Α
Power Dissipation		P_{D}	41	W
Junction Temperature		T_J	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	75	°C/W
Junction to Case	$ heta_{ extsf{JC}}$	3	°C/W

Notes: 1. Pulse width limited by maximum junction temperature.

■ **ELECTRICAL CHARACTERISTICS** (T_C =25°C, unless otherwise specified)

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNII		
OFF CHARACTERISTICS								
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =-250μA, V _{GS} =0V	-40			V		
Drain-Source Leakage Current	I _{DSS}	V _{DS} =-32V, V _{GS} =0V			1			
		V _{DS} =-30V, V _{GS} =0V, T _J =125°C			10	μA		
Gate- Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±250	nA		
On-State Drain Current (Note 1)	$I_{D(ON)}$	V _{DS} =-5V, V _{GS} =-10V	-32			Α		
ON CHARACTERISTICS								
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_D=-250\mu A$	-1	-1.5	-2.5	V		
Static Drain-Source On-State	В	V _{GS} =-4.5V, I _D =-6A		65	94	mΩ		
Resistance (Note 1)	R _{DS(ON)}	V _{GS} =-10V, I _D =-8A		38	55	11122		
Forward Transconductance (Note 1)	g FS	V _{DS} =-10V, I _D =-8A		11		S		
DYNAMIC PARAMETERS								
Input Capacitance	C_{ISS}	V _{GS} =0V, V _{DS} =-25V, f=1MHz		690		pF		
Output Capacitance	Coss			310		pF		
Reverse Transfer Capacitance	C_{RSS}			75		pF		
SWITCHING PARAMETERS (Note 2)								
Total Gate Charge	Q_G			14		nC		
Gate to Source Charge	Q_GS	V _{GS} =-10V, V _{DS} =0.5BV _{DSS} , I _D =-8A		2.2		nC		
Gate to Drain Charge	Q_GD			1.9		nC		
Turn-ON Delay Time	$t_{D(ON)}$			6.7	13.4	ns		
Rise Time	t_R	V_{GS} =-10V, V_{DS} =-20V, I_{D} = -1A, R_{GS} =6 Ω , R_{L} =1 Ω		9.7	19.4	ns		
Turn-OFF Delay Time	t _{D(OFF)}			19.8	35.6	ns		
Fall-Time	$t_{\scriptscriptstyle{F}}$			12.3	22.2	ns		

^{2.} Duty cycle ≤ 1%

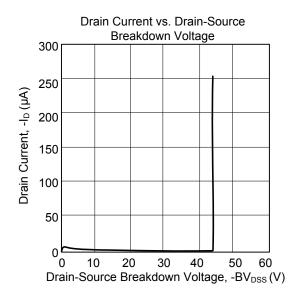
■ ELECTRICAL CHARACTERISTICS (CONT.)

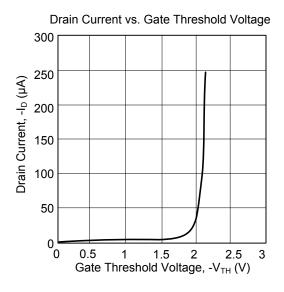
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS								
Drain-Source Diode Forward Voltage (Note 1)	V_{SD}	I _F =I _S , V _{GS} =0V			-1	٧		
Reverse Recovery Time	t _{RR}	L = EA dl /dt=100A/up		15.5		ns		
Reverse Recovery Charge	Q_{RR}	I _F =-5A, dI _F /dt=100A/µs		7.9		nC		
Continuous Current	I _S				-8	Α		
Pulsed Current (Note 3)	I _{SM}				-32	Α		

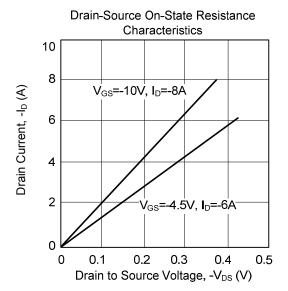
Note: 1. Pulse test: Pulse Width ≤ 300µsec, Duty Cycle ≤ 2%.

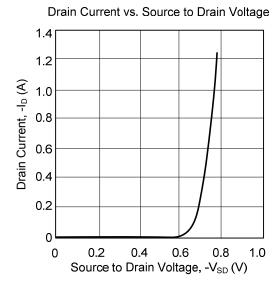
- 2. Independent of operating temperature.
- 3. Pulse width limited by maximum junction temperature.

■ TYPICAL CHARACTERISTICS









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